

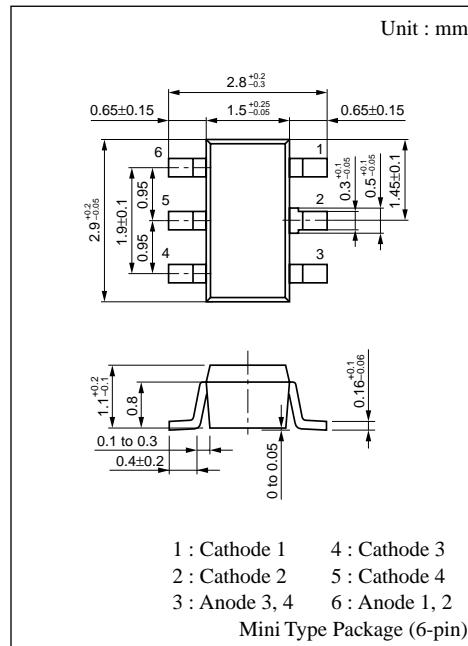
MA122

Silicon epitaxial planer type

For switching circuits

■ Features

- Four-element incorporated in one package, enabling high-density mounting
 - Point-symmetrical wiring, without need of taping direction



■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	V _R	80	V
Peak reverse voltage	V _{RM}	80	V
Forward current (DC)	I _F	* 100	mA
Peak forward current	I _{FM}	* 225	mA
Non-repetitive peak forward surge current	I _{FSM} *	* 500	mA
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

* Value in single diode used

* t=1s

■ Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	I _R	V _R = 75V			100	nA
Forward voltage (DC)	V _F	I _F =100mA			1.2	V
Reverse voltage (DC)	V _R	I _R =100μA	80			V
Terminal capacitance	C _t	V _R = 0V, f=1MHz			15	pF
Reverse recovery time	t _{rr} *	I _F =10mA, V _R = 6V I _{rr} = 0.1 · I _R , R _L =100Ω			10	ns

Note 1. Rated input/output frequency : 100MHz

2. * : t_{IT} measuring circuit

■ Marking

